Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 4.625 inches and 5.625 inches
Function For Which Designed:
Rectifier
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-30
Mounting Method:
Threaded stud
Features Provided:
Reverse polarity
Overall Width Across Flats:
1.047 inches
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 reverse voltage, peak
Current Rating Per Characteristic:
150.00 amperes forward current, average outside diameter
Power Rating Per Characteristic:
180.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0